



# UNIVERSITY OF MINES AND TECHNOLOGY, TARKWA

## SECOND SEMESTER EXAMINATIONS, MAY 2019

**COURSE NO:** MN/MR/GL/GM/MR/PE/ES 162

**COURSE NAME:** APPLIED ELECTRONICS

**CLASS:** MN/MR/GL/GM/MR/PE/ES

**TIME:** 3 HOURS

Name: \_\_\_\_\_ Index Number: \_\_\_\_\_

*Carefully read each question and circle the correct answer.*

*[40 Marks]*

1. The valence electrons possess more energy and are more strongly bound to the atom than inner electrons.
  - a. True
  - b. False
2. Mica, copper and silver are all good conductors.
  - a. True
  - b. False
3. In the saturation mode of operation of the transistor, both the base-emitter junction and the base-collector (BC) junction are forward-biased and the transistor operates as an amplifier.
  - a. True
  - b. False
4. The transfer characteristics of a common-emitter configuration is a graph that shows the relationship between  $I_B$  and  $I_C$ .
  - a. True
  - b. False
5. The conductivity of insulators and semiconductors increases with decrease in temperature.
  - a. True
  - b. False
6. A diode in a half-wave rectifier conducts for  $185^\circ$  of the input cycle.
  - a. True
  - b. False
7. The forward voltage drop for a germanium diode is 0.3 V and for a silicon diode is 0.7 V.
  - a. True
  - b. False
8. The latching current of a thyristor is minimal in value when compared to the holding current.
  - a. True
  - b. False
9. The TRIAC and DIAC are all bidirectional devices.
  - a. True
  - b. False
10. When the thyristor is reversed biased junction J1 and J3 becomes reverse biased the thyristor operates in the forward blocking mode.
  - a. True
  - b. False
11. Positive feedback drives a circuit into oscillation as in various types of oscillator circuit.
  - a. True
  - b. False





## SECTION B [50 Marks]

Answer all questions

1. Figure 1 shows a forward biased silicon diode with an internal dynamic resistance  $r_d$  of  $17\ \Omega$  and a  $R_{LIMIT}$  of  $4.5\ \Omega$ .

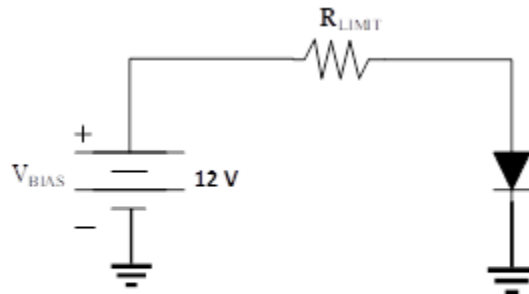


Figure 1 Forward Biased Silicon Diode

Determine the following parameters.

- Forward current ( $I_F$ ) for an ideal silicon diode.
  - Voltage across the limiting resistor for an ideal silicon diode
  - Forward current ( $I_F$ ) for a practical silicon diode.
  - Forward current ( $I_F$ ) for a complete silicon diode.
  - Forward voltage ( $V_F$ ) for the complete silicon diode.
  - Voltage across the limiting resistor for a complete silicon diode
- [6 marks]
2. Find the value of  $I_C$  and the  $\alpha_{DC}$  rating and of the transistor shown in the Figure 2.

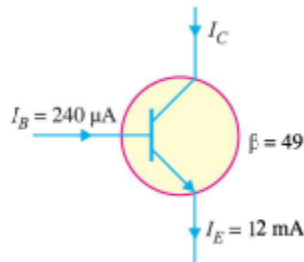


Figure 2

[2 marks]

3. A transistor is connected in common emitter (CE) configuration in which the collector supply is  $8\text{ V}$  and the voltage drop across resistance  $R_C$  connected in the collector circuit is  $0.5\text{ V}$ . The value of  $R_C=800\ \Omega$ . If  $\alpha_{DC}=0.96$ , Calculate the collector emitter voltage and the base current.
- [4 marks]

4. Determine  $V_{CB}$  in the transistor circuit shown in figure 3 below. The Transistor is of silicon and has  $\beta_{DC}=145$ . Draw the dc load line

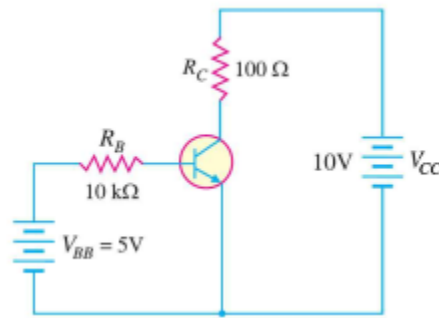


Figure 3

[9 marks]

5. A voltage gain of a voltage series amplifier without feedback is 3000. Calculate the overall voltage gain or the closed loop gain of the amplifier if negative voltage feedback is introduced in the circuit. Given that the feedback gain is 0.01.

[1 mark]

6. Figure 5 shows a non-inverting feedback amplifier. If the gain of the amplifier without feedback is 10,000. find:

- i. Feedback gain  $\beta$
- ii. The overall voltage gain
- iii. Output voltage if the input voltage is 1 mV

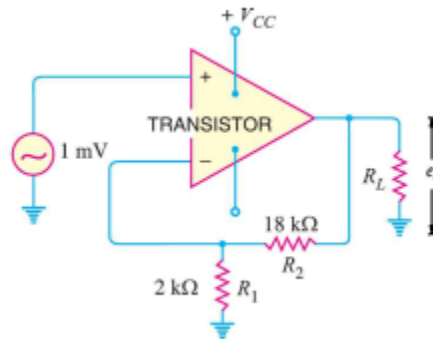


Figure 5

[3 marks]

7. Draw and label the circuit symbol of the following semiconductor device.
- i. Zener diode
  - ii. Npn transistor
  - iii. Operation amplifier
  - iv. Thyristor

[6 marks]

8. Determine the output voltage for the circuit in Figure 6

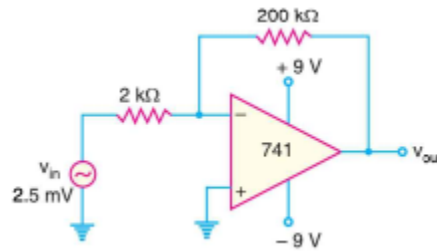


Figure 6

[2 marks]

9. Calculate the output voltage for the circuit in figure 7. The input  $V_1 = 100 \sin(1000t) \text{ mV}$  and  $V_2 = 10 \sin(2500t) \text{ mV}$

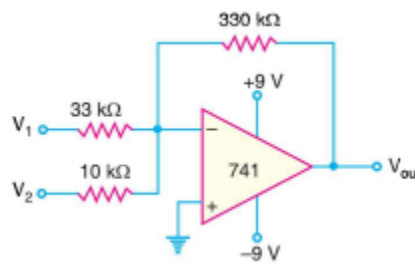


Figure 7

[3 marks]

10. Determine the common-mode gain of an op-amp that has a differential open-loop voltage gain of 200000 and CMRR of 90 decibels.

[2 marks]

11. State four applications of thyristors.

[2 marks]

12. Define the following terms:

- i. Virtual ground
- ii. Instrument
- iii. Common mode rejection ratio
- iv. Input bias current
- v. Accuracy
- vi. DC load line

[6 marks]

13. Draw and label the I-V static characteristics of a thyristor.

[4 marks]

**Examiners: I. Aidoo/ R. A. Ofosu**